MA3S781D (MA781WA), MA3S781E (MA781WK)

Silicon epitaxial planar type

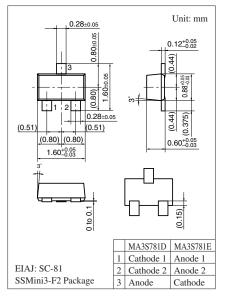
For high speed switching

Features

- Two MA3S781 (MA781) is contained in one package
- High-density mounting is possible
- \bullet Low forward voltage $V_{\rm F}$

| Parameter | | Rating | Unit |
|------------------------------|---|---|--|
| Reverse voltage | | 30 | V |
| Maximum peak reverse voltage | | 30 | V |
| Single | I _F | 30 | mA |
| Double | | 20 | |
| Single | I _{FM} | 150 | mA |
| Double | | 110 | |
| re | Tj | 125 | °C |
| Storage temperature | | -55 to +125 | °C |
| | rse voltage Single Double Single Double re | $\begin{tabular}{ c c c c } \hline & & & & & & \\ \hline & & & & & & \\ \hline Single & & & & & \\ \hline Double & & & & & \\ \hline re & & & T_j & & \\ \hline \end{tabular}$ | $\begin{tabular}{ c c c c c } \hline V_R & V_R & 30 \\ \hline V_{RM} & 30 \\ \hline Single & I_F & 30 \\ \hline Double & 20 \\ \hline Single & I_{FM} & 150 \\ \hline Double & 110 \\ \hline re & T_j & 125 \\ \hline \end{tabular}$ |

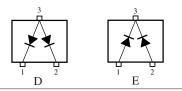
Absolute Maximum Ratings $T_a = 25^{\circ}C$



Marking Symbol

• MA3S781D: M2P • MA3S781E: M2R

Internal Connection



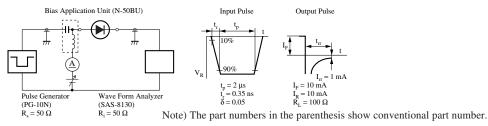
| Parameter | Symbol | Conditions | Min | Тур | Max | Unit |
|-------------------------|-----------------|---|-----|-----|-----|------|
| Forward voltage | V _{F1} | $I_F = 1 \text{ mA}$ | | | 0.4 | V |
| | V _{F2} | I _F = 30 mA | | | 1.0 | |
| Reverse current | I _R | $V_R = 30 V$ | | | 1 | μΑ |
| Terminal capacitance | Ct | $V_{R} = 1 V, f = 1 MHz$ | | 1.5 | | pF |
| Reverse recovery time * | t _{rr} | $I_F = I_R = 10 \text{ mA}$ $I_{rr} = 1 \text{ mA}, R_L = 100 \Omega$ | | 1.0 | | ns |
| Detection efficiency | η | $V_{IN} = 3 V_{(peak)}, f = 30 \text{ MHz}$ $R_L = 3.9 \text{ k}\Omega, C_L = 10 \text{ pF}$ | | 65 | | % |

Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

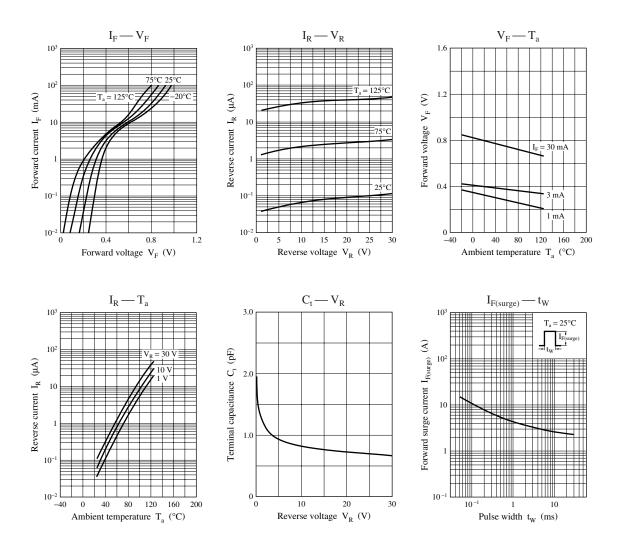
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7031 measuring methods for diodes.

2. This product is sensitive to electric shock (static electricity, etc.). Due attention must be paid on the charge of a human body and the leakage of current from the operating equipment.

3. Absolute frequency of input and output is 2 GHz. 4. *: trr measurement circuit



Panasonic



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